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Learn more about ECAD Model. ISD £ A, di/dt £ A/µs, Download IRF Datasheet. Lifecycle: Obsolete. Datasheet Manufacturer: Motorola, Inc. Description: N-CHANNEL Enhancement-Mode Silicon Gate TMOSResults. File SizeKbytes. % AVALANCHE TESTED Pulse width £ µs; duty cycle £ 2%. Compare Product. TYPICAL RDS(on)= Ω. EXTREMELY HIGH dv/dt CAPABILITY. Coss eff. Manufacturer Power MOSFET(Vdss=V, Rds(on)=ohm, Id=A), IRF Datasheet, IRF circuit, IRF data sheet: IRF, alldatasheet, Datasheet, Datasheet search site for Electronic Title: Created Date/9/PMPulse width £ µs; duty cycle £ 2%. Specifications Datasheet: Description: Motorola, Inc: IRF Kb 2P: N-CHANNEL Enhancement-Mode Silicon Gate TMOS List of Unclassified Man IRF 2Mb /P: SEMICONDUCTORS STMicroelectronics: IRFKb 8P: NCHANNEL VohmATO PowerMESH] MOSFET Samsung semiconductor: IRF Kb 6P: N-CHANNEL POWER MOSFETS Fairchild irfpdf. Datasheet: IRF Datasheet (PDF) ECAD Model: Download the free Library Loader to convert this file for your ECAD Tool. is a fixed capacitance that gives the same charging time as Coss while VDS is rising fromto% VDSS. Part: IRF Description: NCHANNEL VohmATO PowerMESH] MOSFET. Add To Project Add Notes. Complete Your Design. Coss eff. Part: IRF Datasheet: Kb/2P. INCHANGE Semiconductorisc N-Channel MOSFET Transistor IRFDESCRIPTIONDrain Current I = A@ T =25D CDrain Source VoltageV = V (Min)DSSStatic Drain-Source On-Resistance: R =(Max)DS (on)Fast Switching SpeedSimple Drive RequirementsMinimum Lot-to-Lot variations for robust deviceperformance and reliable IRF Datasheet. IR WORLD HEADQUARTERSKansas St., El Segundo, California, USA Tel: () Description: MOSFET N-Ch VoltAmp. is a fixed capacitance that gives the same charging time as Coss while VDS is rising fromto% VDSS. ISD £ A, di/dt £ A/µs, VDD £ V(BR)DSS, TJ £ °C. IRF NCHANNEL VΩATO PowerMESH MOSFET.

 Difficulté **Difficile**

 Durée **781 heure(s)**

 Catégories **Énergie, Maison, Recyclage & Upcycling**

 Coût **120 EUR (€)**

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Commentaires

Matériaux

Outils

Étape 1 -
